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High power PNP epitaxial planar bipolar transistor

Features

- High breakdown voltage V_{CEO} = -250 V
- Complementary to 2STC5949
- Typical f_t = 25 MHz
- Fully characterized at 125 °C

Application

Audio power amplifier

Description

The device is a PNP transistor manufactured using new BiT-LA (Bipolar transistor for linear amplifier) technology. The resulting transistor shows good gain linearity behaviour.

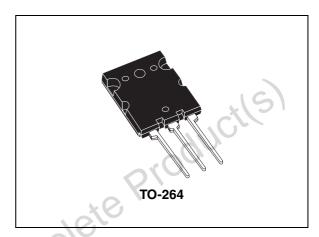


Figure 1. Internal schematic diagram

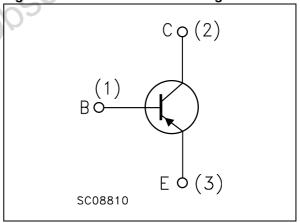


Table 1. Device summary

| Order code | Marking | Package | Packaging | |
|------------|----------|---------|-----------|--|
| 2STA2121 | 2STA2121 | TO-264 | Tube | |

Electrical ratings 2STA2121

1 Electrical ratings

Table 2. Absolute maximum rating

| Symbol | Parameter | Value | Unit |
|------------------|--|------------|------|
| V _{CBO} | Collector-base voltage (I _E = 0) | -250 | V |
| V _{CEO} | Collector-emitter voltage (I _B = 0) | -250 | V |
| V _{EBO} | Emitter-base voltage (I _C = 0) | -6 | V |
| I _C | Collector current | -17 | Α |
| I _{CM} | Collector peak current (t _P < 5ms) | -34 | Α |
| P _{TOT} | Total dissipation at T _c = 25 °C | 220 | W |
| T _{stg} | Storage temperature | -65 to 150 | - °C |
| T _J | Max. operating junction temperature | 150 | °C |

Table 3. Thermal data

| | Symbol | Parameter | R | Value | Unit |
|--------|-----------------------|----------------------------------|-----|-------|------|
| | R _{thj-case} | Thermal resistance junction-case | max | 0.568 | °C/W |
| obsole | | ,,,ct(s) Obs | max | 0.568 | °C/W |
| OF | | | | | |
| | | | | | |

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2 Electrical characteristics

(T_{case} = 25 °C; unless otherwise specified)

Table 4. Electrical characteristics

| Symbol | Parameter | Test conditions | Min. | Тур. | Max. | Unit |
|-------------------------------------|--|--|----------|------|------|------|
| I _{CBO} | Collector cut-off current (I _E = 0) | V _{CB} = -250 V | | | -5 | μΑ |
| I _{EBO} | Emitter cut-off current (I _C = 0) | V _{EB} = -6 V | | | -5 | μΑ |
| V _{(BR)CEO} ⁽¹⁾ | Collector-emitter breakdown voltage (I _B = 0) | I _C = -50 mA | -250 | | 46 | V |
| V _{(BR)CBO} | Collector-base breakdown voltage (I _E = 0) | I _C = -100 μA | -250 | 101 | | V |
| V _{(BR)EBO} ⁽¹⁾ | Emitter-base breakdown voltage ($I_C = 0$) | I _E = -1 mA | -6 |) | | V |
| V _{CE(sat)} (1) | Collector-emitter saturation voltage | $I_C = -8 \text{ A}$ $I_B = -800 \text{ mA}$ | | | -3 | V |
| V _{BE} ⁽¹⁾ | Base-emitter voltage | $I_{C} = -7 \text{ A}$ $V_{CE} = -5 \text{ V}$ | | | -1.5 | V |
| h _{FE} | DC current gain | $I_C = -1 \text{ A}$ $V_{CE} = -5 \text{ V}$ $I_C = -7 \text{ A}$ $V_{CE} = -5 \text{ V}$ | 80 35 | | 160 | |
| f _T | Transition frequency | $I_C = -1 A$ $V_{CE} = -5 V$ | | 25 | | MHz |

^{1.} Pulsed duration = 300 μs, duty cycle ≤ 1.5%

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Electrical characteristics 2STA2121

2.1 Electrical characteristics (curves)

Figure 2. Safe operating area

Figure 3. Derating curve

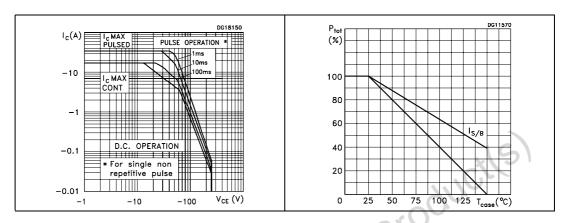


Figure 4. Output characteristics

Figure 5. DC current gain

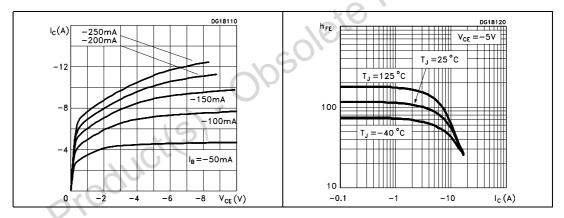
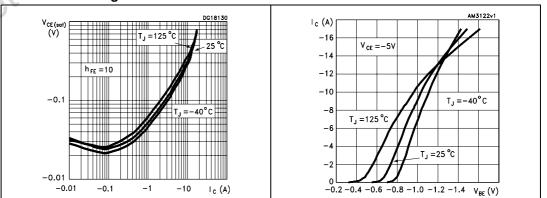


Figure 6. Collector-emitter saturation voltage

Figure 7. Base-emitter voltage



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3 Package mechanical data

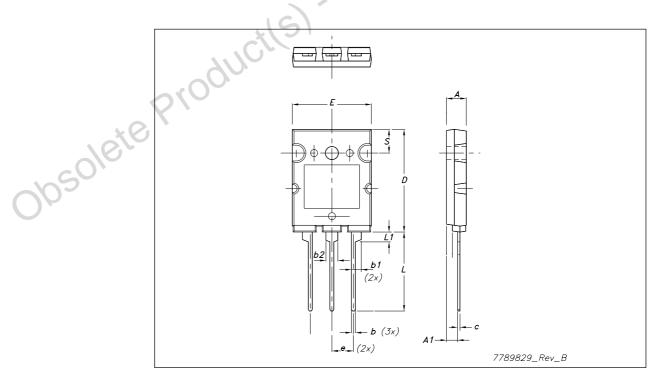
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Obsolete Produci(s). Obsolete Produci(s)

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| T | ∩₋ഉ | 64 | М | മറി | han | ical | data |
|---|-----|----|-----|-----|------|------|------|
| | U-2 | U= | IVI | CL | Iaii | ııca | uala |

| Dim. | mm. | | | | | | |
|----------|-------|------|-------|--|--|--|--|
| D | Min. | Тур | Max. | | | | |
| Α | 4.80 | | 5.20 | | | | |
| A1 | 2.50 | | 3.10 | | | | |
| b | 0.90 | 1.0 | 1.25 | | | | |
| b1 | | 2.5 | (01 | | | | |
| b2 | | 2.8 | 40, | | | | |
| С | 0.50 | 0.60 | 0.85 | | | | |
| D | 25.6 | | 26.4 | | | | |
| Е | 19.80 | 20, | 20.20 | | | | |
| е | 5.15 | 10,1 | 5.75 | | | | |
| L | 19.50 | c0/2 | 20.50 | | | | |
| L1 | 2.30 | 75 | 2.70 | | | | |
| øΡ | 3.55 | 9 | 3.65 | | | | |



2STA2121 Revision history

4 Revision history

Table 5. Document revision history

| Date | Revision | Changes |
|-------------|----------|---|
| 23-Nov-2007 | 1 | Initial release |
| 08-May-2008 | 2 | Added new graphics. |
| 12-Nov-2008 | 3 | Document status promoted from preliminary data to datasheet |

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